# LIST OF PUBLICATIONS

## JOURNAL PAPERS: (Total Impact Factor: 116.657 (2024))

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[3] Tanushree Saha, Sneha Ray, Rohit Biswas, Soutik Mondal, Sourav Sarkar, Debarghya Paul, Kanta Bhattacheryya, Palash Das, Anshuman Sarkar, and **Aritra Acharyya**, "Matrix-Coupled LED–CdS Photoresistor Arrays: Fabrication, Optical–Electronic Coupling Modelling, and Wide-Range Programmable Resistance Characteristics," Journal of Electronic Materials, Springer [USA], vol. 55, pp. 4658-4672, 2026. **(Impact Factor: 2.500 (2024))**

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